

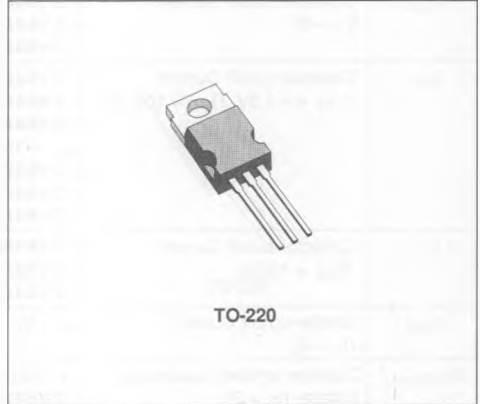
## POWER LINEAR AND SWITCHING APPLICATIONS

### DESCRIPTION

The 2N6486, 2N6487 and 2N6488 are silicon epitaxial-base NPN transistors mounted in Jedec TO-220 plastic package.

They are intended for use in power linear and switching applications.

The complementary PNP types are the 2N6489, 2N6490 and 2N6491 respectively.



### INTERNAL SCHEMATIC DIAGRAMS



### ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	NPN PNP*			Unit
		2N6486 2N6489	2N6487 2N6490	2N6488 2N6491	
$V_{CBO}$	Collector-base Voltage ( $I_E = 0$ )	50	70	90	V
$V_{CEX}$	Collector-base Voltage ( $V_{BE} = 1.5V$ ; $R_{BE} = 100\Omega$ )	50	70	90	V
$V_{CEO}$	Collector-base Voltage ( $I_B = 0$ )	40	60	80	V
$V_{EBO}$	Emitter-base Voltage ( $I_C = 0$ )	5			V
$I_C$	Collector Current	15			A
$I_B$	Base-current	5			A
$P_{Tot}$	Total Power Dissipation at $T_{case} \leq 25^\circ C$ $T_{case} \leq 25^\circ C$	75			W
		1.8			W
$T_{stg}$	Storage Temperature	- 65 to 150			$^\circ C$
$T_j$	Junction Temperature	150			$^\circ C$

\* For NPN types voltage and current values are negative.

## THERMAL DATA

$R_{th(j-case)}$	Thermal Resistance Junction-case	Max	1.67	°C/W
$R_{th(j-amb)}$	Thermal Resistance Junction-ambient	Max	70	°C/W

ELECTRICAL CHARACTERISTICS ( $T_{case} = 25^{\circ}C$  unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
$I_{CEO}$	Collector-cutoff Current ( $I_B = 0$ )	for <b>2N6486/89</b> $V_{CE} = 20V$ for <b>2N6487/90</b> $V_{CE} = 30V$ for <b>2N6488/91</b> $V_{CE} = 40V$			1 1 1	mA mA mA
$I_{CEX}$	Collector-cutoff Current ( $V_{BE} = -1.5V$ , $R_{BE} = 100\Omega$ )	for <b>2N6486/89</b> $V_{CE} = 45V$ for <b>2N6487/90</b> $V_{CE} = 65V$ for <b>2N6488/91</b> $V_{CE} = 85V$ $T_{case} = 150^{\circ}C$ for <b>2N6486/89</b> $V_{CE} = 40V$ for <b>2N6487/90</b> $V_{CE} = 60V$ for <b>2N6488/91</b> $V_{CE} = 80V$			0.5 0.5 0.5 5 5 5	mA mA mA mA mA mA
$I_{CER}$	Collector-cutoff Current ( $R_{BE} = 100\Omega$ )	for <b>2N6486/89</b> $V_{CE} = 35V$ for <b>2N6487/90</b> $V_{CE} = 55V$ for <b>2N6488/91</b> $V_{CE} = 75V$			0.5 0.5 0.5	mA mA mA
$I_{EBO}$	Emitter-cutoff Current ( $I_C = 0$ )	$V_{EB} = 5V$			1	mA
$V_{CEO(sus)}^*$	Collector-emitter Sustaining Voltage ( $I_B = 0$ )	$I_C = 200mA$ for <b>2N6486/89</b> for <b>2N6487/90</b> for <b>2N6488/91</b>	40 60 80			V V V
$V_{CER(sus)}^*$	Collector-emitter Sustaining Voltage ( $R_{BE} = 100\Omega$ )	$I_C = 200mA$ for <b>2N6486/89</b> for <b>2N6487/90</b> for <b>2N6488/91</b>	45 65 85			V V V
$V_{CEX(sus)}^*$	Collector-emitter Sustaining Voltage ( $V_{BE} = -1.5V$ , $R_{BE} = 100\Omega$ )	$I_C = 200mA$ for <b>2N6486/89</b> for <b>2N6487/90</b> for <b>2N6488/91</b>	50 70 90			V V V
$V_{CE(sat)}^*$	Collector-emitter Saturation Voltage	$I_C = 5A$ $I_B = 0.5A$ $I_C = 15A$ $I_B = 5A$			1.3 3.5	V V
$V_{BE}^*$	Base-emitter Voltage	$I_C = 5A$ $V_{CE} = 4V$ $I_C = 15A$ $V_{CE} = 4V$			1.3 3.5	V V
$h_{FE}^*$	DC Current Gain	$I_C = 5A$ $V_{CE} = 4V$ $I_C = 15A$ $V_{CE} = 4V$	20 5		150	
$h_{ie}$	Small Signal Current Gain	$I_C = 1A$ $V_{CE} = 4V$ $f = 1MHz$ $I_C = 1A$ $V_{CE} = 4V$ $f = 1KHz$	5 25			

\* Pulsed : pulse duration = 300us, duty cycle  $\leq 2\%$ .  
For PNP types voltage and current values are negative.